300V PNP SMALL-SIGNAL TRANSISTOR IN SOT23

Description

This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirements of automotive applications.

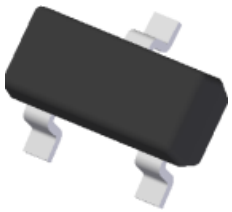
Features

- BV_{CEO} > -300V
- Ideal for Medium Power Amplification and Switching
- Complementary NPN Type: MMBTA42Q
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The AMBTA92Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.**
  https://www.diodes.com/quality/product-definitions/

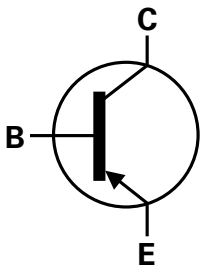
Mechanical Data

- Package: SOT23
- Package Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish-Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.008 grams (Approximate)

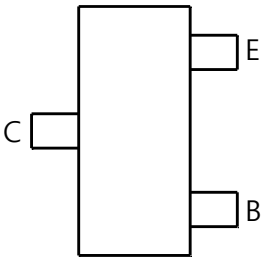
SOT23



Top View



Device Symbol



Top View
Pinout

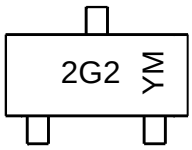
Ordering Information (Note 4)

Orderable Part Number	Package	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
					Qty.	Carrier
AMBTA92Q-7	SOT23	2G2	7	8	3,000	Reel

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

SOT23



2G2 = Product Type Marking Code
YM = Date Code Marking
Y or $\overline{Y}$ or $\underline{Y}$ = Year (ex: M = 2025)
M = Month (ex: 9 = September)

Date Code Key

Year	2018	-	2025	2026	2027	2028	2029	2030	2031	2032	2033	2034
Code	F	-	M	N	P	R	S	T	U	V	W	X

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-300	V
Collector-Emitter Voltage	V_{CEO}	-300	V
Emitter-Base Voltage	V_{EBO}	-5.0	V
Collector Current	I_C	-500	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 5)	P_D	300	mW
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{\theta JA}$	417	°C/W
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to +150	°C

ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

Notes: 5. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.
6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)					
Collector-Base Breakdown Voltage	BV_{CBO}	-300	—	V	I_C = -100µA
Collector-Emitter Breakdown Voltage	BV_{CEO}	-300	—	V	I_C = -1.0mA
Emitter-Base Breakdown Voltage	BV_{EBO}	-5.0	—	V	I_E = -100µA
Collector Cut-Off Current	I_{CBO}	—	-250	nA	V_{CB} = -200V
Emitter Cut-Off Current	I_{EBO}	—	-100	nA	V_{EB} = -3.0V
ON CHARACTERISTICS (Note 7)					
DC Current Gain	h_{FE}	25 40 25	— — —	—	I_C = -1.0mA, V_{CE} = -10V I_C = -10mA, V_{CE} = -10V I_C = -30mA, V_{CE} = -10V
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	—	-0.5	V	I_C = -20mA, I_B = -2.0mA
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	—	-0.9	V	I_C = -20mA, I_B = -2.0mA
SMALL-SIGNAL CHARACTERISTICS					
Output Capacitance	C_{obo}	—	6.0	pF	V_{CB} = -20V, f = 1.0MHz, I_E = 0
Current Gain-Bandwidth Product	f_T	50	—	MHz	V_{CE} = -20V, I_C = -10mA, f = 100MHz

Note: 7. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.

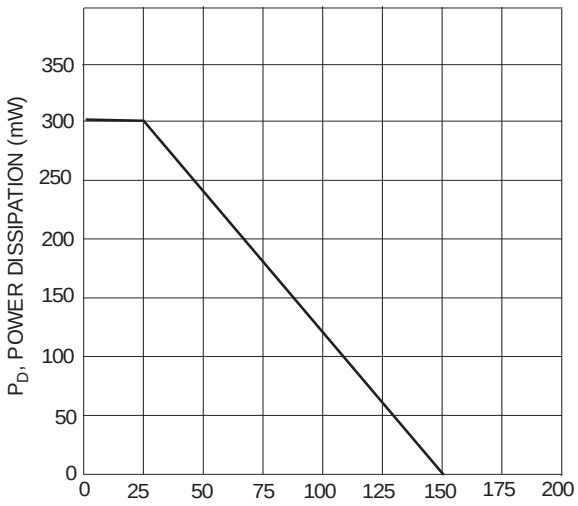


Fig. 1Power Dissipation
vs. Ambient Temperature

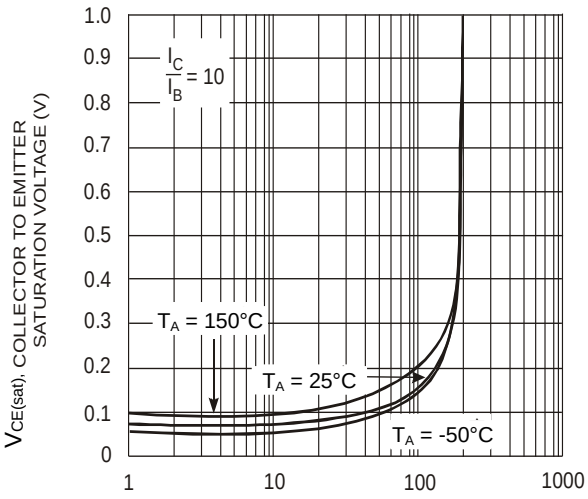


Fig. 2, Collector Emitter Saturation Voltage
vs. Collector Current

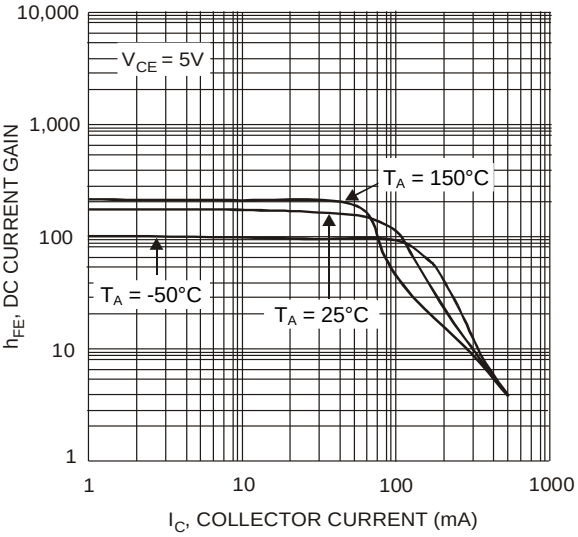


Fig. 3, DC Current Gain vs
Collector Current

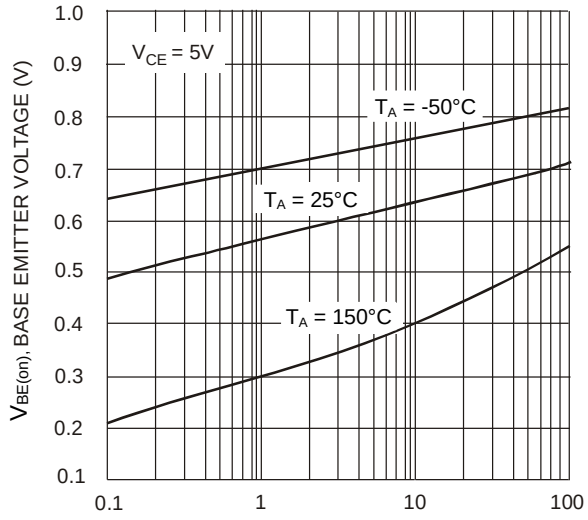


Fig. 4, Base Emitter Voltage vs Collector Current

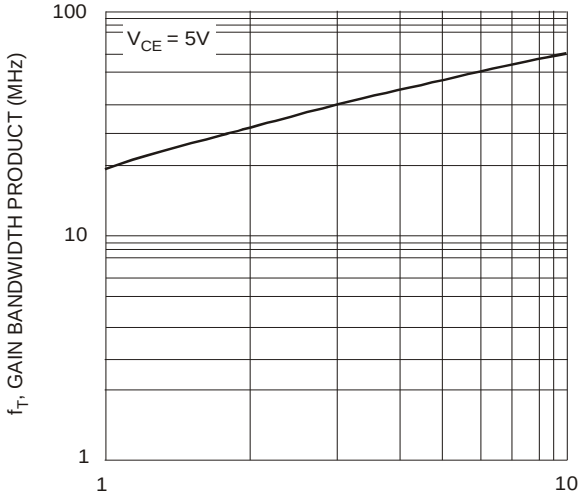


Fig. 5, Gain Bandwidth Product vs
Collector Current

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

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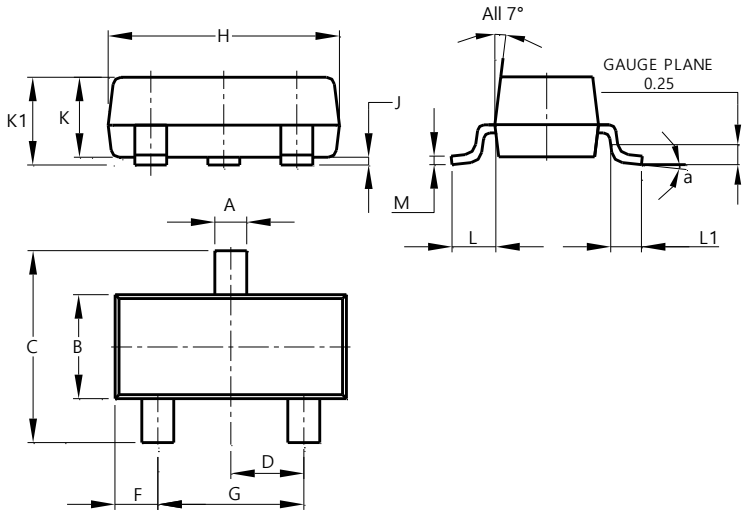
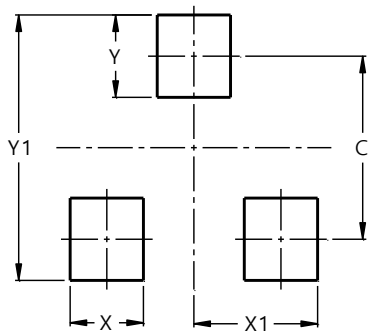


SOT23			
Dim	**Min**	**Max**	**Typ**
A	0.37	0.51	0.40
B	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
H	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
M	0.085	0.150	0.110
a	0°	8°	--
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



Dimensions	Value (in mm)
C	2.0
X	0.8
X1	1.35
Y	0.9
Y1	2.9

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.

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